NSN 5962-01-219-9569

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.02 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Bipolar and programmed and schottky and high impedance and w/enable and w/buffered output and electrostatic sensitive
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Current Rating Per Characteristic:
155.00 milliamperes supply
Product Name:
Prom with uncommitted collector
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
80.00 nanoseconds propagation delay time, high to low level output and 80.00 nanoseconds propagation delay time, low to high level
output
Memory Device Type:
Prom
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0